

Technical Data Data Sheet N1168, Rev. - **Green Products** 

# Power Surface Mount Schottky Rectifier (20V, 120Amp)

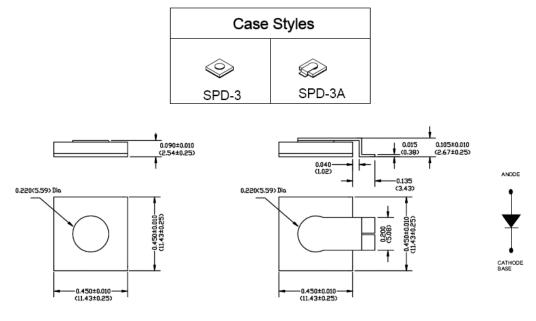
#### **Applications:**

- Switching power supply
- Converters
- Reverse battery protection
- Redundant power subsystems
- Many other high current AC/DC power supplies

#### Features:

- 150 °C T<sub>J</sub> operation
- Low forward voltage drop
- Low reverse leakage current
- High surge capacities
- High frequency operation
- Guaranteed reverse avalanche capability
- Low profile surface mount package
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### Mechanical Dimensions: In Inches / mm



SPD-3

SPD-3A



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### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	20	V
Average Forward Current	I <sub>F(AV)</sub>	50% duty cycle, rectangular wave form	120	A
Peak One Cycle Non-Repetitive Surge Current (per leg)	I <sub>FSM</sub>	8.3 ms, half Sine pulse	1650	A

## **Electrical Characteristics:**

Characteristics	Symbol	Condition	Max.	Units
Forward Voltage Drop(per leg) *	V <sub>F1</sub>	@ 120A, Pulse, T <sub>J</sub> = 25 °C	0.48	V
	V <sub>F2</sub>	@ 120A, Pulse, T <sub>J</sub> = 125 °C	0.35	V
Reverse Current (per leg) *	I <sub>R1</sub>	$@V_{R} = rated V_{R}$ , Pulse,	12	mA
		T <sub>J</sub> = 25 °C		
	I <sub>R2</sub>	$@V_{R} = rated V_{R}$ , Pulse,	1320	mA
		T <sub>J</sub> = 125 °C		
Junction Capacitance	CJ	@V <sub>R</sub> = 5V, T <sub>C</sub> = 25 °C	8100	pF
(per leg)		f <sub>SIG</sub> = 1MHz ,Vsig=50mV(p-p)		

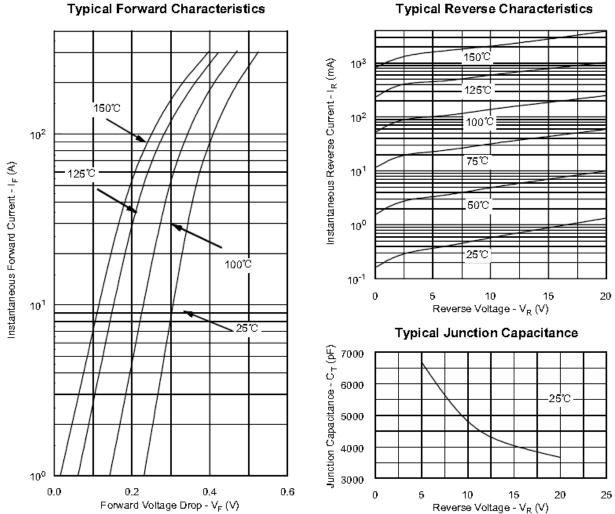
\* Pulse Width < 300µs, Duty Cycle <2%

# **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature	TJ	-	-55 to +150	°C
Max. Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Maximum Thermal	R <sub>0JC</sub>	DC operation	0.20	°C/W
Resistance Junction to Case				-C/VV
Case Style	SPD-3/A			



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# Typical Reverse Characteristics

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